

# UC2842AQ, UC2843AQ, UC2844AQ, UC2845AQ Current-mode PWM Controller

## 1 Features

- Extended temperature performance of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$
- Optimized for off-line and dc to dc converters
- Low start up current ( $<0.5\text{mA}$ )
- Trimmed oscillator discharge current
- Automatic feed forward compensation
- Pulse-by-pulse current limiting
- Enhanced load response characteristics
- Under-voltage lockout with hysteresis
- Double pulse suppression
- High current totem pole output
- Internally trimmed bandgap reference
- 500kHz operation
- Low  $r_o$  error amp

## 2 Applications

- Switch mode power supplies (SMPS)
- [DC-DC converters](#)
- [Power modules](#)
- Industrial PSU
- Battery operated PSU

## 3 Description

The UC2842A/3A/4A/5A family of control ICs is a pin for pin compatible improved version of the UC2842/3/4/5 family. Providing the necessary features to control current mode switched mode power supplies, this family has the following improved features. Start up current is designed to be less than 0.5mA. Oscillator discharge is trimmed to 8.3mA. During under voltage lockout, the output stage can sink at least 10mA at less than 1.2V for  $V_{CC}$  over 5V.

The difference between members of this family are shown in the table below.

### Package Information

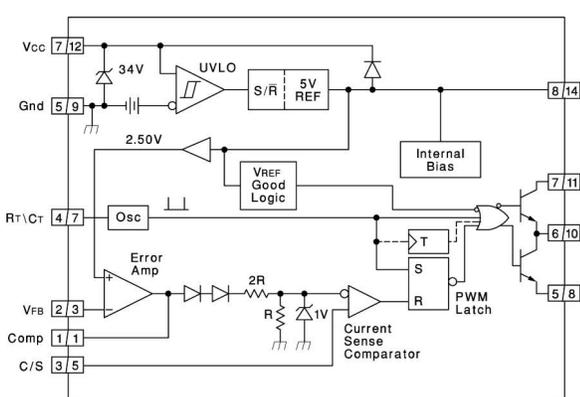
PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
UC2842A, UC2843A, UC2844A, UC2845A	D (SOIC, 8)	4.90mm × 6.00mm
	D (SOIC, 14)	8.65mm × 6.00mm

- (1) For all available packages, see [Section 11](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.

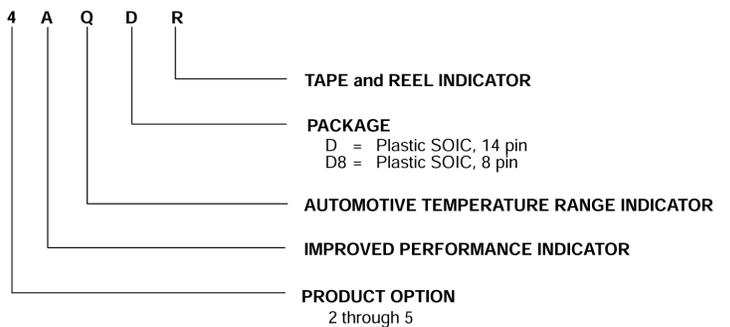
### Device Information

PART NUMBER <sup>(1)</sup>	UVLO ON	UVLO OFF	MAXIMUM DUTY CYCLE
UC2842A	16V	10V	<100%
UC2843A	8.5V	7.9V	<100%
UC2844A	16V	10V	<50%
UC2845A	8.5V	7.9V	<50%

- (1) For all available packages, see the orderable addendum at the end of the data sheet.



**Functional Diagram**



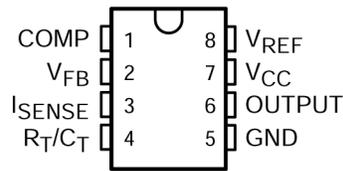
### Ordering Information



## Table of Contents

<b>1 Features</b> .....	1	<b>8 Application and Implementation</b> .....	11
<b>2 Applications</b> .....	1	8.1 Application Information.....	11
<b>3 Description</b> .....	1	<b>9 Device and Documentation Support</b> .....	13
<b>4 Pin Configuration and Functions</b> .....	3	9.1 Receiving Notification of Documentation Updates....	13
<b>5 Specifications</b> .....	5	9.2 Support Resources.....	13
5.1 Absolute Maximum Ratings.....	5	9.3 Trademarks.....	13
5.2 ESD Ratings.....	5	9.4 Electrostatic Discharge Caution.....	13
5.3 Electrical Characteristics.....	6	9.5 Glossary.....	13
5.4 Typical Characteristics.....	7	<b>10 Revision History</b> .....	13
<b>6 Parameter Measurement Information</b> .....	8	<b>11 Mechanical, Packaging, and Orderable Information</b> .....	13
<b>7 Detailed Description</b> .....	10		
7.1 Functional Block Diagram.....	10		

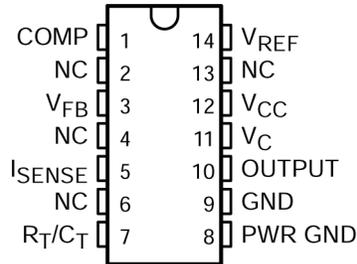
## 4 Pin Configuration and Functions



**Figure 4-1. D 8-Pin Package (Top View)**

**Table 4-1. Pin Functions**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
COMP	1	O	Outputs the low impedance 1-MHz internal error amplifier that is also the input to the peak current limit or PWM comparator, with an open-loop gain (AVOL) of 90 dB. This pin is capable of sinking a maximum of 6 mA and is not internally current limited.
V <sub>FB</sub>	2	I	Input to the error amplifier that can be used to control the power converter voltage feedback loop for stability
I <sub>SENSE</sub>	3	I	Input to the peak current limit, PWM comparator of the controllers. When used in conjunction with a current sense resistor, the error amplifier output voltage controls the power systems cycle-by-cycle peak current limit. The maximum peak current sense signal is internally clamped to 1 V. See the Functional Block Diagram
R <sub>T</sub> /C <sub>T</sub>	4	I	Input to the internal oscillator that is programmed with an external timing resistor (RT) and timing capacitor (CT). See Oscillator for information on properly selecting these timing components. TI recommends using capacitance values from 470 pF to 4.7 nF. TI also recommends that the timing resistor values chosen be from 5 kΩ to 100 kΩ.
GND	5	GND	Controller signal ground.
OUTPUT	6	O	Output of 1-A totem pole gate driver. This pin can sink and source up to 1 A of gate driver current. A gate driver resistor must be used to limit the gate driver current.
V <sub>CC</sub>	7	I	Analog controller bias input that provides power to the device. Total VCC current is the sum of the quiescent VCC current and the average OUTPUT current. Knowing the switching frequency and the MOSFET gate charge, Qg, the average OUTPUT current can be calculated from: $I_{OUTPUT} = Q_g \times f_{SW}$ A bypass capacitor, typically 0.1 μF, connected directly to GROUND with minimal trace length, is required on this pin. An additional bypass capacitor at least 10 times greater than the gate capacitance of the main switching FET used in the design is also required on VCC.
V <sub>REF</sub>	8	O	Bias input to the gate driver. This pin must have a biasing capacitor that is at least 10 times greater than the gate capacitance of the main switching FET used in the design.



**Figure 4-2. D 14-Pin Package (Top View)**

**Table 4-2. Pin Functions**

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
COMP	1	I/O	Error amplifier compensation pin
NC	2	-	Do not connect
VFB	3	I	Error amplifier input
NC	4	-	Do not connect
ISENSE	5	I	Current sense comparator input
NC	6	-	Do not connect
RT/CT	7	I/O	Oscillator RC input
PWR GND	8	GND	Output PWM ground terminal
GND	9	GND	Device power supply ground terminal
OUTPUT	10	O	PWM Output
V <sub>S</sub>	11	-	Output PWM positive voltage supply
V <sub>CC</sub>	12	-	Device positive voltage supply
NC	13	-	Do not connect
V <sub>REF</sub>	14	O	Oscillator voltage reference

(1) I = Input, O = Output, I/O = Input or Output, GND = Ground.

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2)</sup>

	MIN	MAX	UNIT
V <sub>CC</sub> voltage (low impedance source)		30	V
V <sub>CC</sub> voltage (I <sub>CC</sub> mA)	self limiting		
Output current I <sub>O</sub>		±1	A
Output energy (capacitive load)		5	μJ
Analog Inputs (pins 3, 5)	-0.3	6.3	V
Error Amp Output Sink current		10	mA
Power Dissipation at T <sub>A</sub> < +25°C (D package)		1	W
Package thermal impedance: D (8-pin) package θ <sub>JA</sub> (see <sup>(3)</sup> ):	Typical 117.4		°C/W
Storage temperature range T <sub>stg</sub>	-65	150	°C
Lead temperature soldering 1.6 mm (1/16 inch) from case for 10 seconds		300	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Unless otherwise indicated, voltages are reference to ground and currents are positive into and negative out of the specified terminals.
- (3) Long term high-temperature storage and/or extended use at maximum recommended operating conditions can result in a reduction of overall device life. See [http://www.ti.com/ep\\_quality](http://www.ti.com/ep_quality) for additional information on enhanced plastic packaging.

### 5.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Electrical Characteristics

$T_A = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $V_{CC} = 15\text{ V}$  <sup>(1)</sup>,  $R_T = 10\text{ k}\Omega$ ,  $C_T = 3.3\text{ nF}$ , and  $T_A = T_J$  (unless otherwise stated)

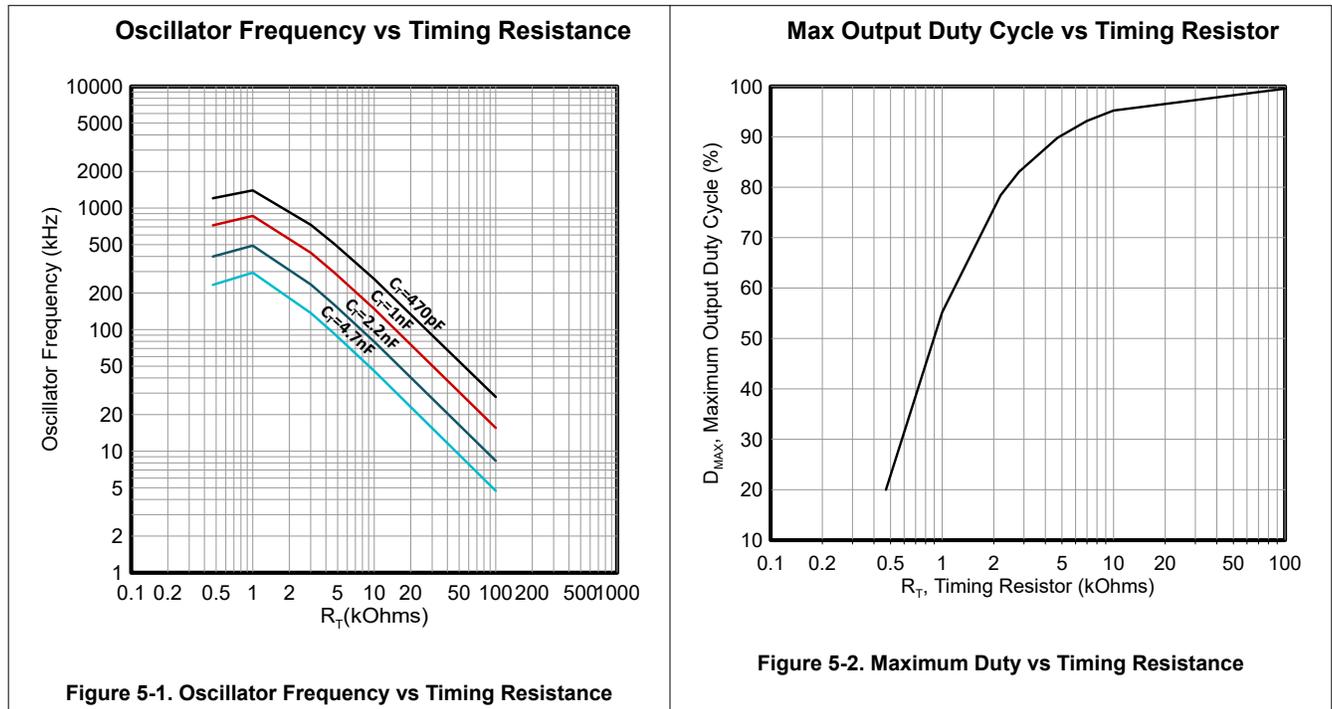
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Reference Section</b>					
Output voltage	$T_J = 25^{\circ}\text{C}$ , $I_O = 1\text{ mA}$	4.95	5.0	5.05	V
Line regulation voltage	$V_{IN} = 12\text{ V}$ to $25\text{ V}$		6	20	mV
Load regulation voltage	$I_O = 1\text{ mA}$ to $20\text{ mA}$		6	25	mV
Temperature stability	See Notes 2 and 3		0.2	0.4	mV/ $^{\circ}\text{C}$
Total output variation voltage	Line, Load, Temp.	4.9		5.1	V
Output noise voltage	$f = 10\text{ Hz}$ to $10\text{ kHz}$ , <sup>(2)</sup> $T_J = 25\text{ C}$		50		$\mu\text{V}$
Long term stability	1000 hours, <sup>(2)</sup> $T_A = 125^{\circ}\text{C}$		5	25	mV
Output short-circuit current		-30	-100	-180	mA
<b>Oscillator Section</b>					
Initial accuracy	See <sup>(4)</sup> $T_J = 25\text{ C}$	47	52	57	kHz
Voltage stability	$V_{CC} = 12\text{ V}$ to $25\text{ V}$		0.2	1	%
Temperature stability	$T_A = \text{MIN}$ to $\text{MAX}$ , <sup>(2)</sup>		5		%
Amplitude peak-to-peak	V pin 7, <sup>(2)</sup>		1.7		V
Discharge current	$T_J = 25\text{ C}$	7.8	8.3	8.8	
	V pin 7 = $2\text{ V}$ , <sup>(3)</sup> $T_J = \text{Full range}$	7.5		8.8	mA
<b>Error Amplifier Section</b>					
Input voltage	COMP = $2.5\text{ V}$	2.45	2.5	2.55	V
Input bias current			-0.3	-1	$\mu\text{A}$
Open loop voltage gain ( $A_{VOL}$ )	$V_O = 2\text{ V}$ to $4\text{ V}$	65	90		dB
Unity gain bandwidth	$T_J = 25^{\circ}\text{C}$ <sup>(2)</sup>	0.7	1		MHz
PSRR	$V_{CC} = 12\text{ V}$ to $25\text{ V}$	60	70		dB
Output sink current	FB = $2.7\text{ V}$ , COMP = $1.1\text{ V}$	2	6		mA
Output source current	FB = $2.3\text{ V}$ , COMP = $5\text{ V}$	-0.5	-0.8		mA
VOU high	FB = $2.3\text{ V}$ , $R_L = 15\text{ k}\Omega$ to GND	5	6		V
VOU low	FB = $2.7\text{ V}$ , $R_L = 15\text{ k}\Omega$ to $V_{REF}$		0.7	1.1	V
<b>Current Sense Section</b>					
Gain	<sup>(3)</sup> and <sup>(4)</sup>	2.85	3	3.15	V/V
Maximum input signal	COMP = $5\text{ V}$ , <sup>(3)</sup>	0.9	1	1.1	V
PSRR	$V_{CC} = 12\text{ V}$ to $25\text{ V}$ , <sup>(3)</sup>		70		dB
Input bias current			-2	-10	$\mu\text{A}$
Delay to output	$I_{SENSE} = 0\text{ V}$ to $2\text{ V}$ , <sup>(2)</sup>		150	300	ns
<b>Output Section (OUT)</b>					
Low-level output voltage	$I_{OUT} = 20\text{ mA}$		0.1	0.4	V
	$I_{OUT} = 200\text{ mA}$		1.5	2.2	
High-level output voltage	$I_{OUT} = -20\text{ mA}$	13	13.5		V
	$I_{OUT} = -200\text{ mA}$	12	13.5		
Rise time	$C_L = 1\text{ nF}$ , <sup>(2)</sup> $T_J = 25\text{ C}$		25	150	ns
Fall time	$C_L = 1\text{ nF}$ , <sup>(2)</sup> $T_J = 25\text{ C}$		25	150	ns
UVLO saturation	$V_{CC} = 5\text{ V}$ , $I_{OUT} = 10\text{ mA}$		0.7	1.2	V
<b>Undervoltage Lockout Section</b>					
Start threshold	UC2842A, UC2844A	15	16	17	V
	UC2843A, UC2845A	7.8	8.4	9	

$T_A = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $V_{CC} = 15\text{ V}$  <sup>(1)</sup>,  $R_T = 10\text{ k}\Omega$ ,  $C_T = 3.3\text{ nF}$ , and  $T_A = T_J$  (unless otherwise stated)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Minimum operation voltage after turn on	UC2842A, UC2844A	9	10	11	V
	UC2843A, UC2845A	7	7.6	8.2	
<b>PWM Section</b>					
Maximum duty cycle	UC2842A, UC2843A	92	96	100	%
	UC2844A, UC2845A	46	48	50	
Minimum duty cycle				0	%
<b>Total Standby Current</b>					
Start-up current			0.3	0.5	mA
Operating supply current	FB = 0 V, SENSE = 0 V		11	17	mA
$V_{CC}$ internal Zener voltage	ICC = 25 mA	30	39		V

- (1) Adjust  $V_{CC}$  above the start threshold before setting at 15 V.
- (2) Not production tested.
- (3) Parameter measured at trip point of latch with  $V_{FB}$  at 0 V.
- (4) Gain is defined by:  $A = \frac{\Delta V_{COMP}}{\Delta V_{SENSE}}$ ; 0 v  $V_{SENSE}$  v 0.8 V.

### 5.4 Typical Characteristics



## 6 Parameter Measurement Information

Error Amp can source and sink up to 0.5 mA, and sink up to 2 mA.

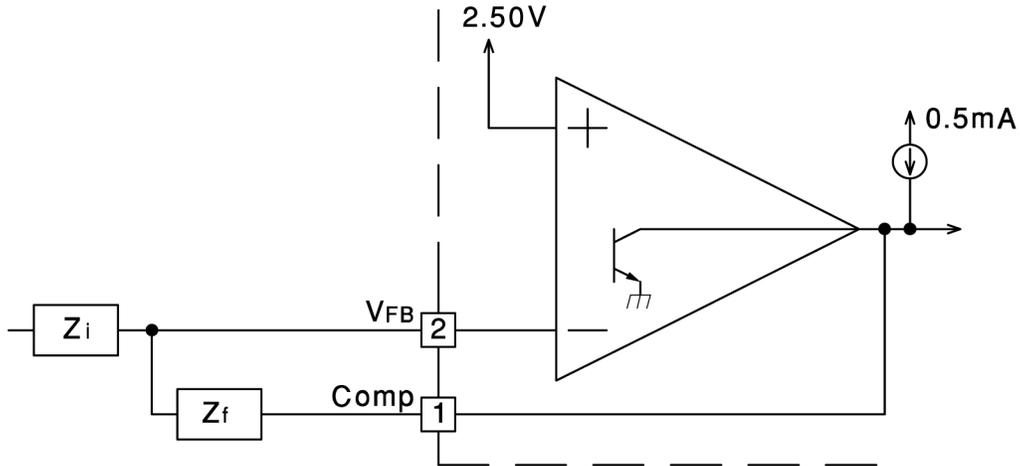


Figure 6-1. Error Amp Configuration

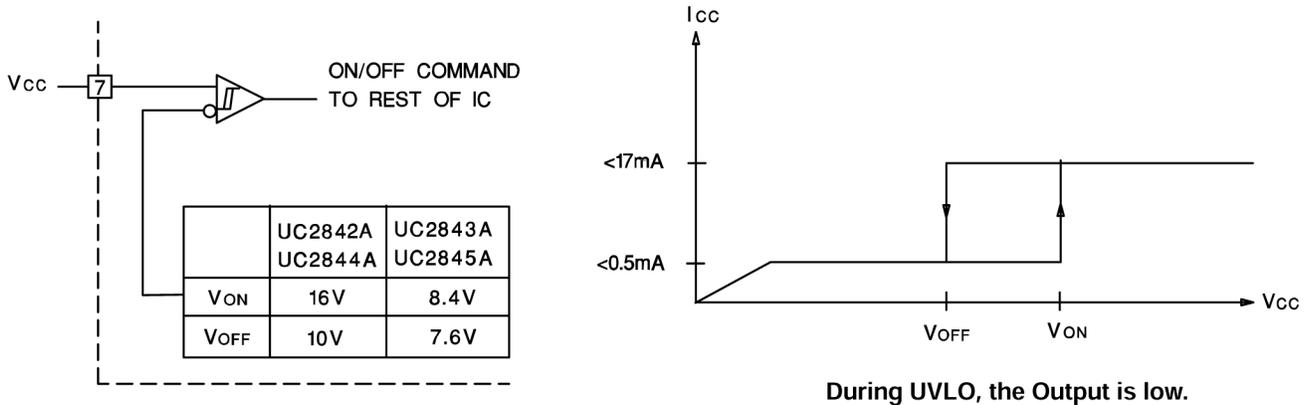
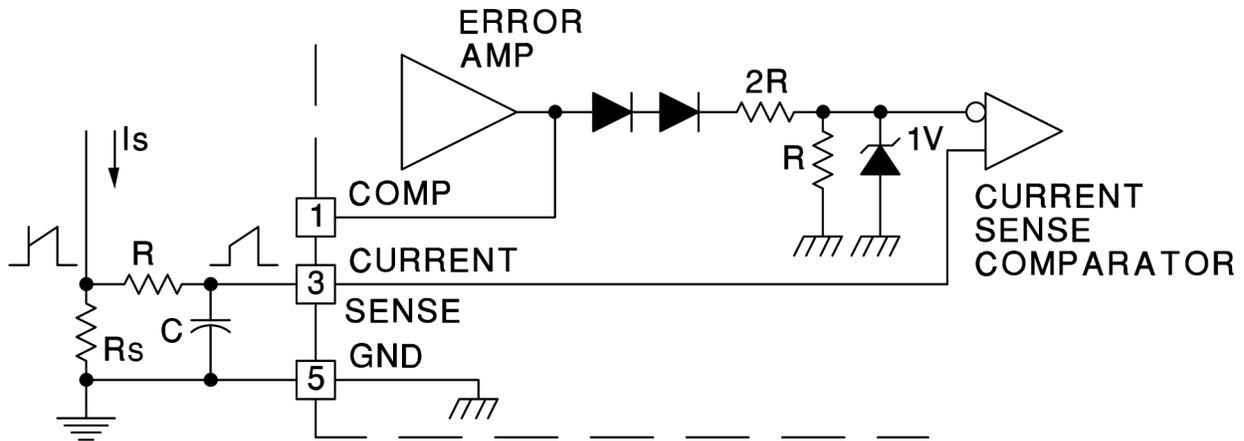


Figure 6-2. Under Voltage Lockout

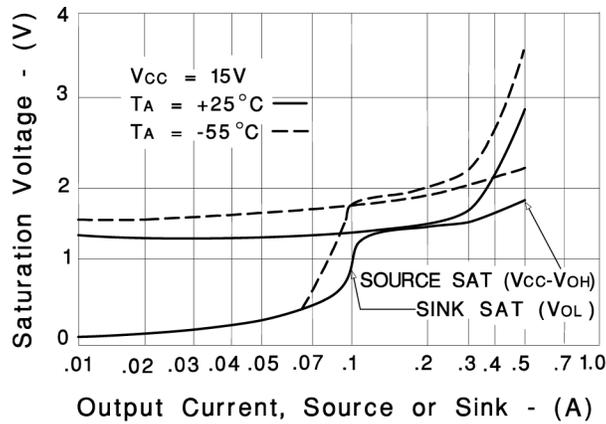


Peak Current ( $I_s$ ) is Determined By The Formula:

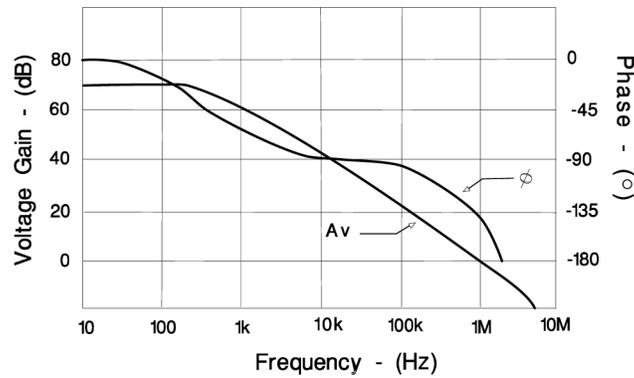
$$I_{smax} = \frac{1.0V}{R_S}$$

A small RC filter may be required to suppress switch transients.

**Figure 6-3. Current Sense Circuit**



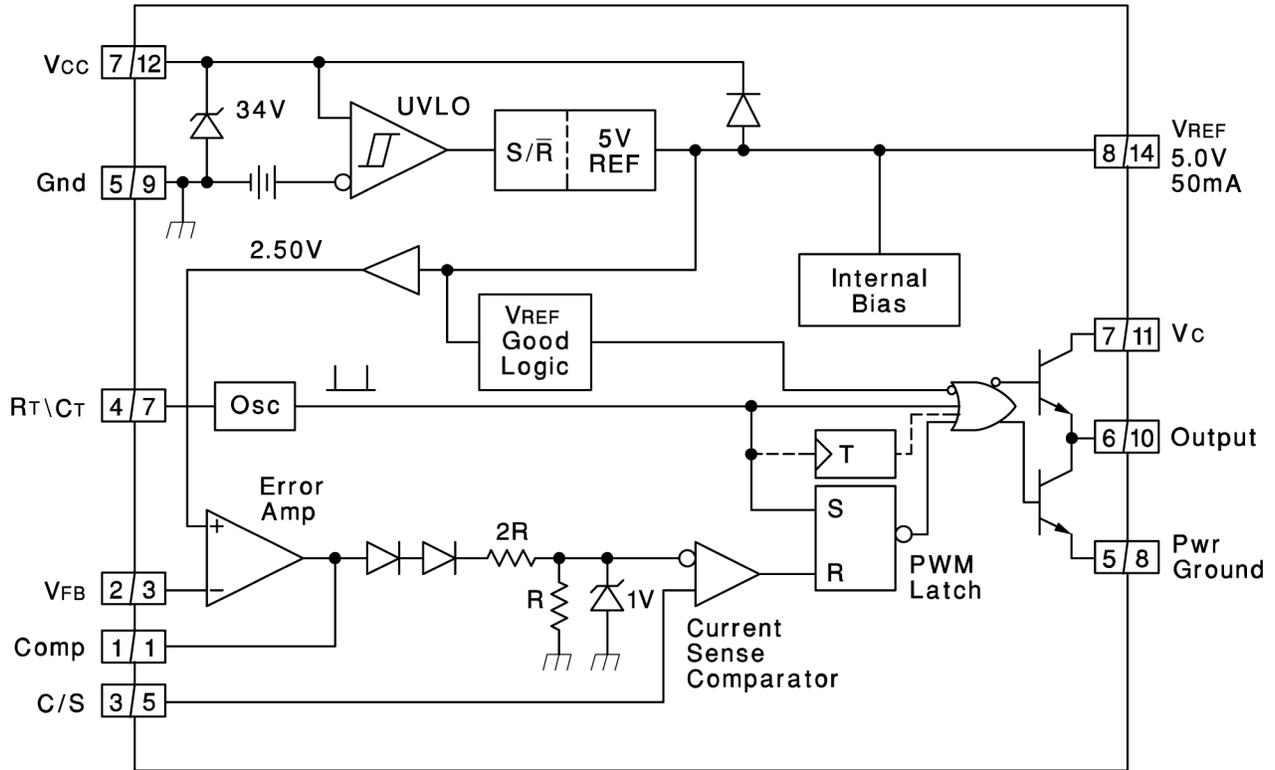
**Figure 6-4. Output Saturation Characteristics**



**Figure 6-5. Error Amplifier Open-Loop Frequency Response**

## 7 Detailed Description

### 7.1 Functional Block Diagram



#### Note

A = DIL-8 Pin Number. B = SO-14 Pin Number.  
 Toggle flip flop used only in 2844A and 2845A.

## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

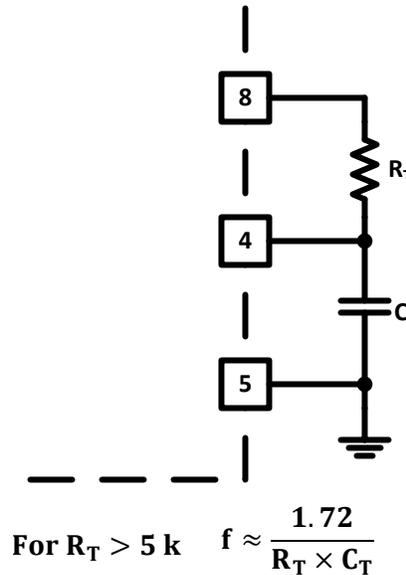


Figure 8-1. Oscillator

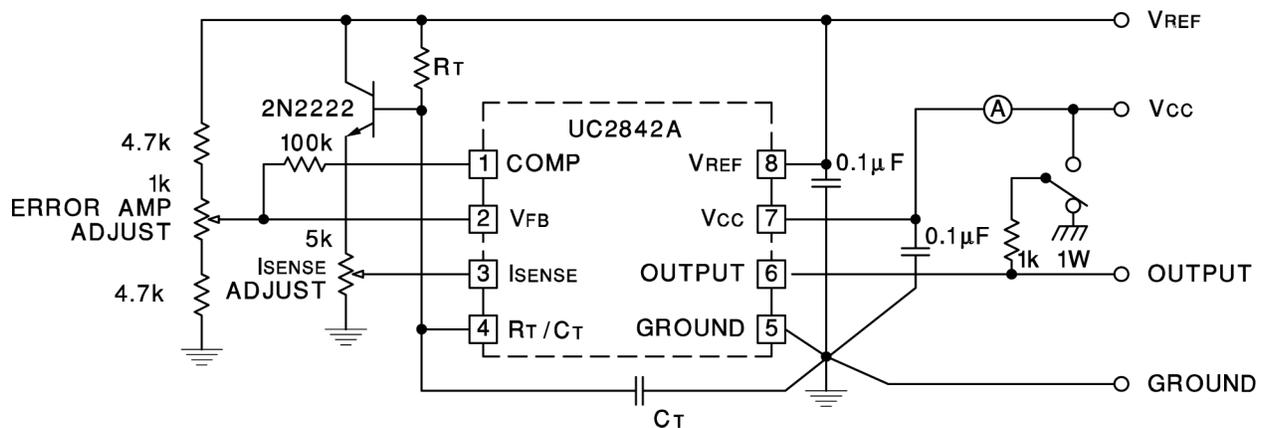


Figure 8-2. Open-Loop Laboratory Text Fixture

High peak currents associated with capacitive loads necessitate careful grounding techniques. Timing and bypass capacitors must be connected close to pin 5 in a single point ground. The transistor and 5k potentiometer are used to sample the oscillator waveform and apply an adjustable ramp to pin 3.



## 9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.2 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.  
All trademarks are the property of their respective owners.

### 9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (April 2003) to Revision A (October 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Changed in Absolute Maximum ratings: Lead temperature soldering, 10s from 260°C to 300°C.....	5
• Added ESD Ratings table, HBM = ±2000V; CDM = ±1500V.....	5
• Changed in Electrical Characteristics table, OUTPUT SECTION: Rise and fall time, typical value from 50ns to 25ns.....	6
• Changed in Electrical Char. table, PWM SECTION: maximum duty cycle of UC2842/3A, minimum value from 94% to 92%.....	6
• Changed in Electrical Char. table, PWM SECTION: maximum duty cycle of UC2844/5A, minimum value from 47% to 46%.....	6
• Changed Electrical Char. table, TOTAL STANDBY CURRENT, VCC Zener voltage, typical value from 34V to 39V.....	6
• Added Typical Characteristics section.....	7
• Updated the Frequency vs Rt and Maximum Duty Cycle vs Rt graphs in the Typical Characteristics section..	7

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">UC2842AQD8</a>	Obsolete	Production	SOIC (D)   8	-	-	Call TI	Call TI	-40 to 125	(2842AQ, UC2842AQ)
<a href="#">UC2842AQD8R</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2842AQ, UC2842AQ)
UC2842AQD8R.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2842AQ, UC2842AQ)
<a href="#">UC2842AQDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2842AQ, UC2842AQ)
UC2842AQDR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2842AQ, UC2842AQ)
<a href="#">UC2843AQD8</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2843AQ, UC2843AQ)
UC2843AQD8.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2843AQ, UC2843AQ)
<a href="#">UC2843AQD8R</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2843AQ, UC2843AQ)
UC2843AQD8R.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2843AQ, UC2843AQ)
<a href="#">UC2843AQDR</a>	Obsolete	Production	SOIC (D)   14	-	-	Call TI	Call TI	-40 to 125	(2843AQ, UC2843AQ)
<a href="#">UC2844AQD8R</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2844AQ, UC2844AQ)
UC2844AQD8R.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	See UC2844AQD8R	(2844AQ, UC2844AQ)
<a href="#">UC2845AQD8R</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2845AQ, UC2845AQ)
UC2845AQD8R.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2845AQ, UC2845AQ)
<a href="#">UC2845AQDR</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2845AQ, UC2845AQ)
UC2845AQDR.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(2845AQ, UC2845AQ)

(1) **Status:** For more details on status, see our [product life cycle](#).

- (2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- (4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC2842AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2842AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2842AQDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
UC2842AQDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
UC2843AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2844AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2844AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2845AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2845AQD8R	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
UC2845AQDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
UC2845AQDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UC2842AQD8R	SOIC	D	8	2500	367.0	367.0	35.0
UC2842AQD8R	SOIC	D	8	2500	356.0	356.0	35.0
UC2842AQDR	SOIC	D	14	2500	356.0	356.0	35.0
UC2842AQDR	SOIC	D	14	2500	353.0	353.0	32.0
UC2843AQD8R	SOIC	D	8	2500	356.0	356.0	35.0
UC2844AQD8R	SOIC	D	8	2500	353.0	353.0	32.0
UC2844AQD8R	SOIC	D	8	2500	356.0	356.0	35.0
UC2845AQD8R	SOIC	D	8	2500	367.0	367.0	35.0
UC2845AQD8R	SOIC	D	8	2500	356.0	356.0	35.0
UC2845AQDR	SOIC	D	14	2500	356.0	356.0	35.0
UC2845AQDR	SOIC	D	14	2500	353.0	353.0	32.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
UC2843AQD8	D	SOIC	8	75	506.6	8	3940	4.32
UC2843AQD8.A	D	SOIC	8	75	506.6	8	3940	4.32

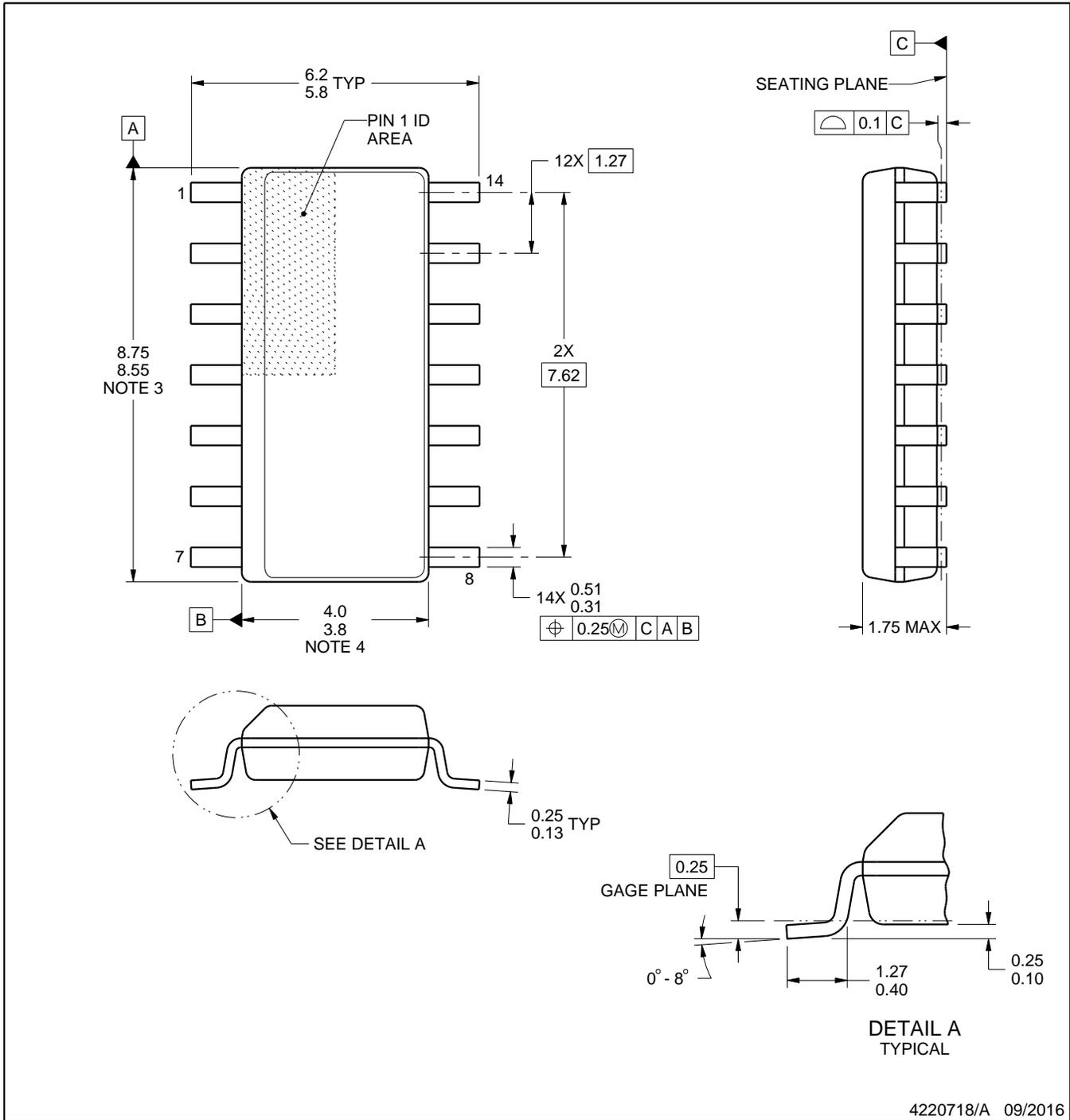
D0014A



# PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

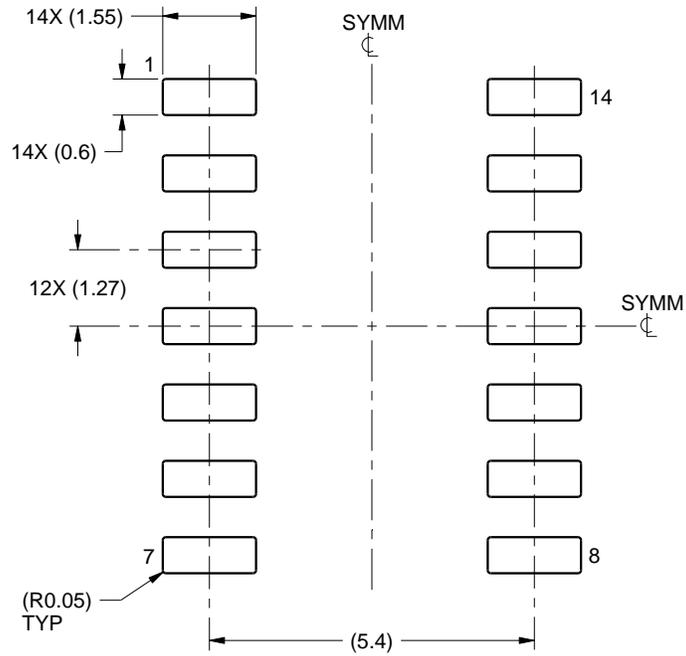
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

# EXAMPLE BOARD LAYOUT

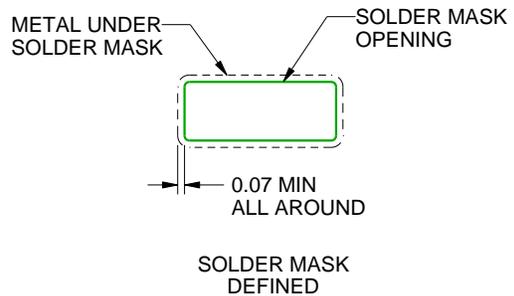
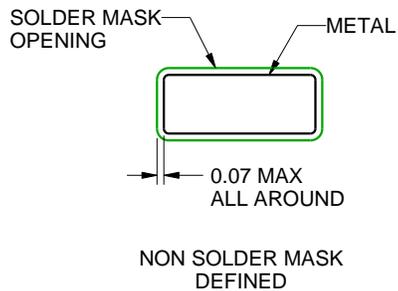
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

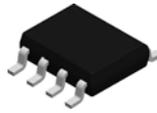
4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



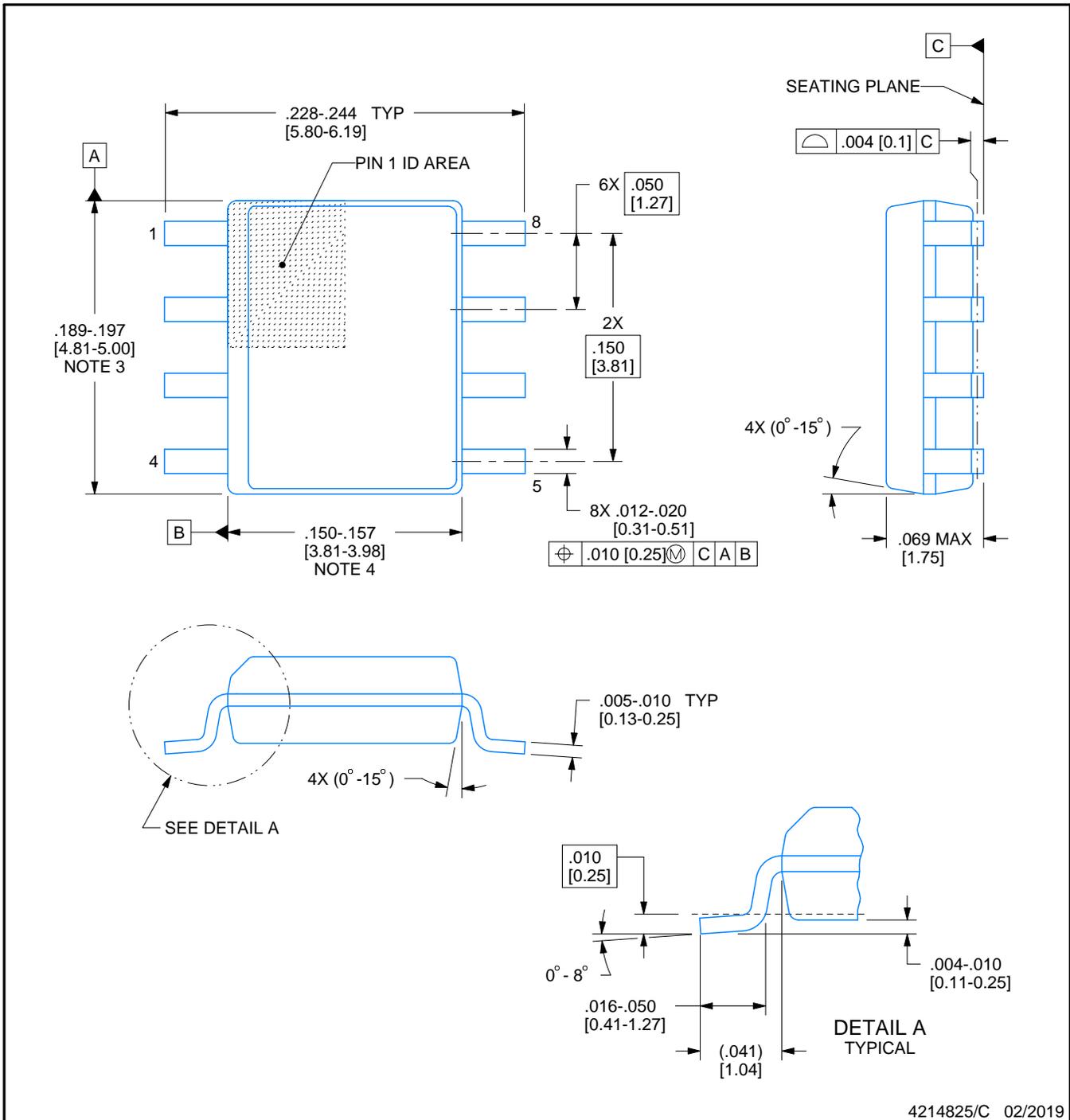


D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

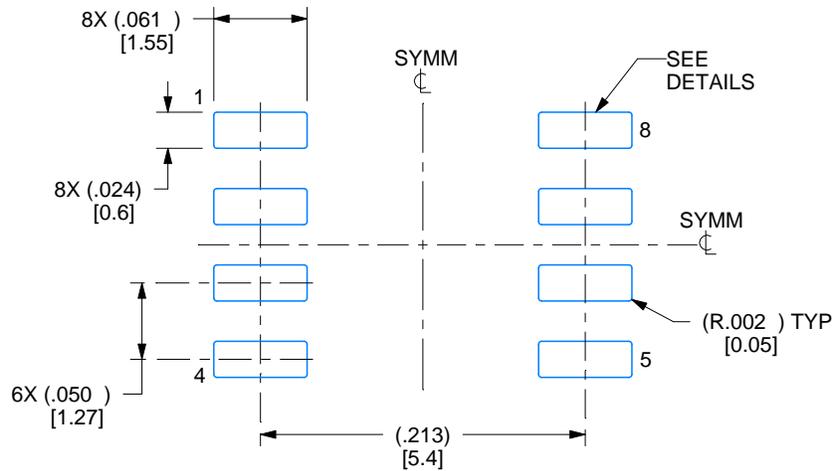
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed  $.006$  [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

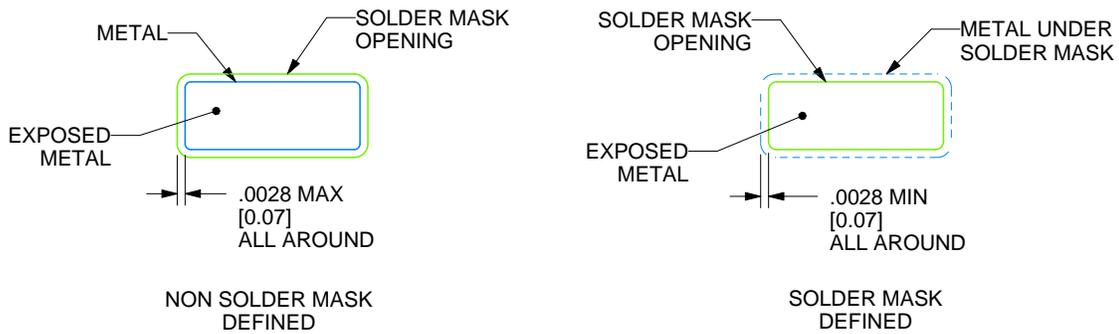
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

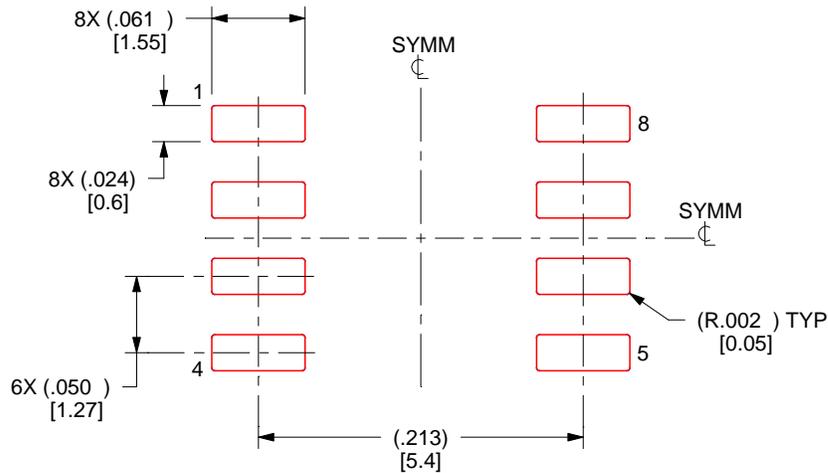
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2025, Texas Instruments Incorporated